2SC3858

Silicon NPN Triple Diffused Planar Transistor (Complement to type 2SA1494)

Application: Audio and General Purpose

Absolute maximum ratings (1a=25°C)							
Symbol	2SC3858	Unit					
Vсво	200	V					
VCEO	200	V					
VEBO	6	V					
Ic	17	А					
Ів	5	А					
Pc	200(Tc=25°C)	W					

150

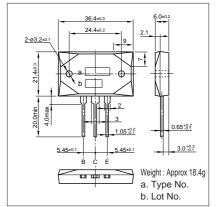
-55 to +150

Τj

Tstg

Electrical C	haracteristics	(Ta=25°C)				
Symbol	Conditions	2SC3858	Unit			
Ісво	Vcb=200V	100max	μΑ			
I EBO	VEB=6V	100max	μΑ			
V(BR)CEO	Ic=50mA	200min	V			
hfe	Vce=4V, Ic=8A	50min*				
Vce(sat)	Ic=10A, IB=1A	2.5max	V			
fт	Vce=12V, Ie=-1A	20typ	MHz			
Сов	VcB=10V, f=1MHz	300typ	pF			
*hre Rank Y(50 to 100), P(70 to 140), G(90 to 180)						

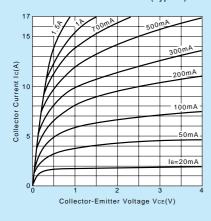
External Dimensions MT-200



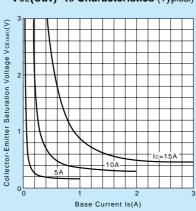
Typical Switching Characteristics (Common Emitter)

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Vcc (V)	RL (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	IB1 (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
40	4	10	10	-5	1	-1	0.5typ	1.8typ	0.6typ

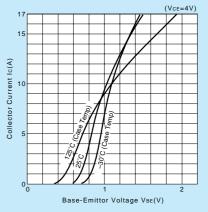
Ic-VcE Characteristics (Typical)



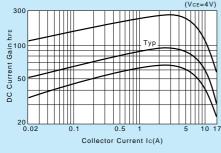
VcE(sat)-IB Characteristics (Typical)



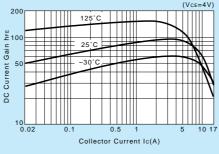
Ic-VBE Temperature Characteristics (Typical)



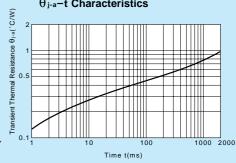
hfe-Ic Characteristics (Typical)



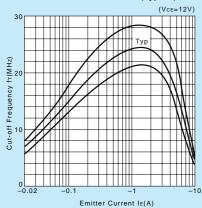
hfe-Ic Temperature Characteristics (Typical)



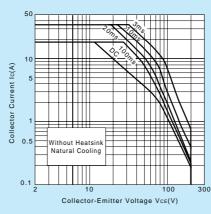
θ_{j-a}-t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

